Thyristor Semiconductor Device - Page 1 of 2



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Inclosure Material:	
Metal	
Overall Length:	
0.505 inches	
Overall Diameter:	
0.544 inches	
End Application:	
F-14 tomcat aircraft. V	elocity pool repairable pieve parts.
Mounting Facility Qu	antity:
1	
Internal Configuratio	n:
Junction contact	
Joint Electronic Devi	ice Engineering Council/jedec/case Outline Designation:
To-48	
Electrode Internally-	electrically Connected To Case:
Anode	
Mounting Method:	
Threaded stud	
Features Provided:	
Hermetically sealed ca	ase
Overall Width Across	s Flats:
0.562 inches	
Thread Size:	
0.250 inches	
Criticality Code Just	ification:
Feat	
Semiconductor Mate	rial:
Silicon	
/oltage Rating In Vo	Its Per Characteristic:
3.0 gate trigger voltag	je, dc
Current Rating Per C	characteristic:
80.00 milliamperes for	ward current, total rms preset
Maximum Operating	Tempurature Per Measurement Point:
125.0 degrees celsius	ambient air
Special Features:	
Weapon system esser	ntial
Test Data Document	:
82577-925909 drawing	g (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any specifica	ation, standard or other document that may be referenced in a basic governing drawing)
Thread Series Desig	nator:
Unf	
Terminal Type And G	Quantity:

2 tab, solder lug

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Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0